

TOSHIBA Transistor Silicon NPN Epitaxial Type (Darlington power transistor)

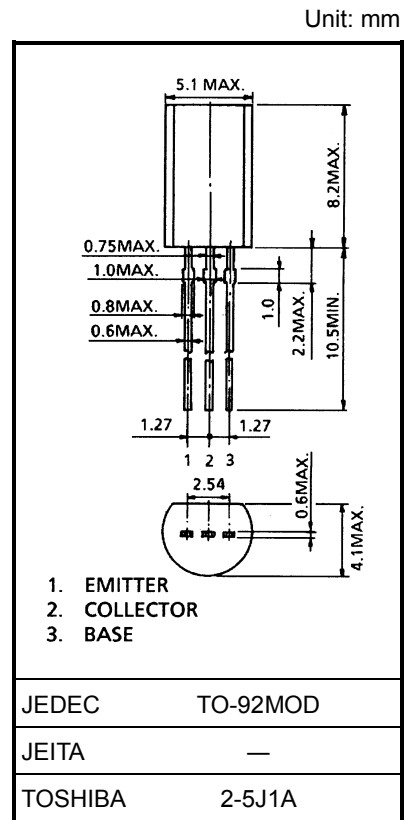
# 2SD2088

Micro Motor Drive, Hammer Drive Applications  
 Switching Applications  
 Power Amplifier Applications

- High DC current gain:  $hFE = 2000$  (min) ( $V_{CE} = 2\text{ V}$ ,  $I_C = 1\text{ A}$ )
- Low saturation voltage:  $V_{CE(sat)} = 1.5\text{ V}$  (max) ( $I_C = 1\text{ A}$ ,  $I_B = 1\text{ mA}$ )
- Zener diode included between collector and base.

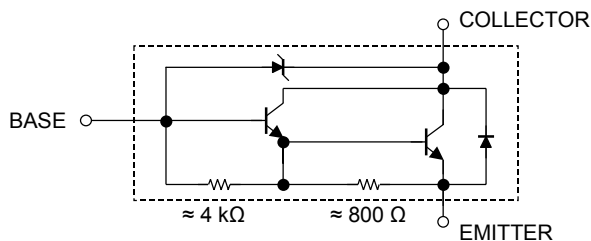
### Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	$60 \pm 10$	V
Collector-emitter voltage	$V_{CEO}$	$60 \pm 10$	V
Emitter-base voltage	$V_{EBO}$	8	V
Collector current	$I_C$	2	A
Base current	$I_B$	0.5	A
Collector power dissipation	$P_C$	0.9	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

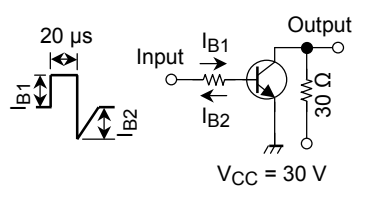


Weight: 0.36 g (typ.)

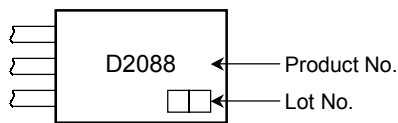
### Equivalent Circuit



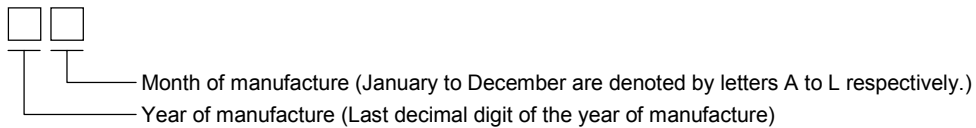
## Electrical Characteristics (Ta = 25°C)

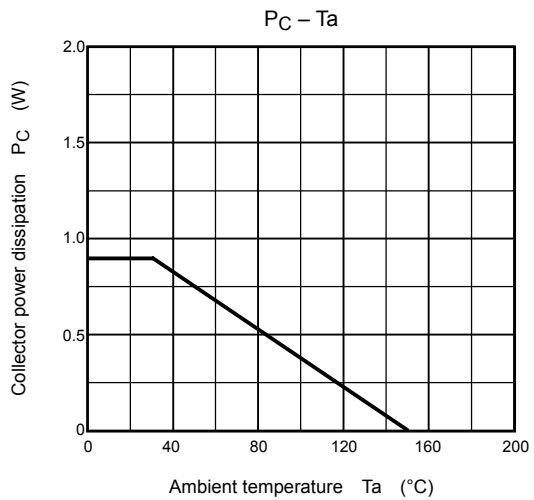
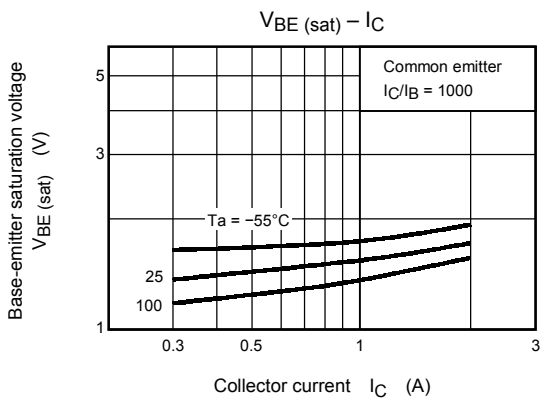
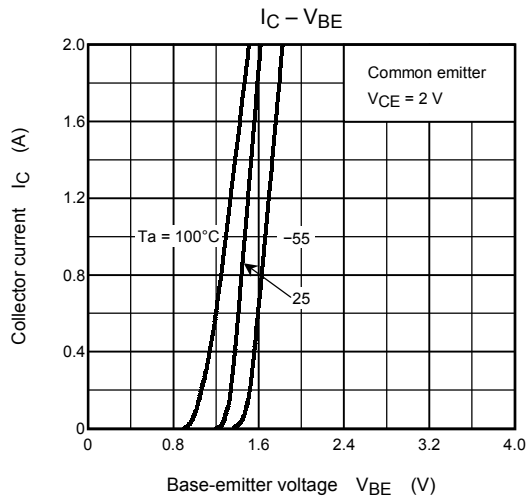
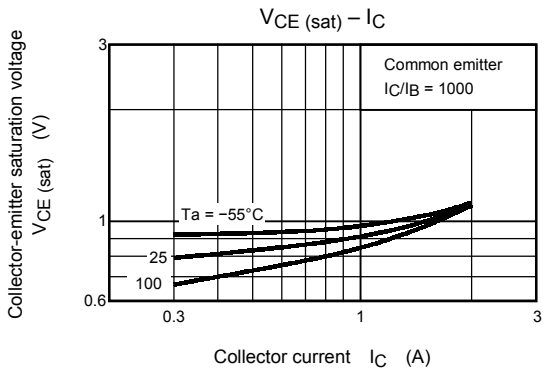
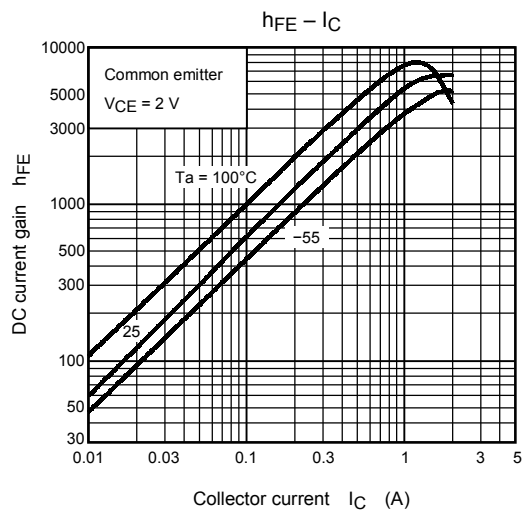
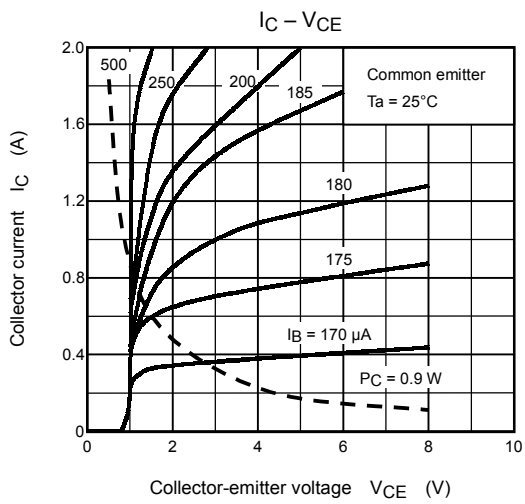
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		$I_{CBO}$	$V_{CB} = 45\text{ V}, I_E = 0$	—	—	10	$\mu\text{A}$
Emitter cut-off current		$I_{EBO}$	$V_{EB} = 8\text{ V}, I_C = 0$	—	—	4	$\text{mA}$
Collector-emitter breakdown voltage		$V_{(BR)CEO}$	$I_C = 10\text{ mA}, I_B = 0$	50	60	70	$\text{V}$
DC current gain		$h_{FE}$	$V_{CE} = 2\text{ V}, I_C = 1\text{ A}$	2000	—	—	
Collector-emitter saturation voltage		$V_{CE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	1.5	$\text{V}$
Base-emitter saturation voltage		$V_{BE(sat)}$	$I_C = 1\text{ A}, I_B = 1\text{ mA}$	—	—	2.0	$\text{V}$
Transition frequency		$f_T$	$V_{CE} = 2\text{ V}, I_C = 0.5\text{ A}$	—	100	—	$\text{MHz}$
Collector output capacitance		$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	20	—	$\text{pF}$
Unclamped inductive load energy		$E_{S/B}$	$L = 10\text{ mH}, I_C = 1.3\text{ A}, I_B = \pm 50\text{ mA}$	8.4	—	—	$\text{mJ}$
Switching time	Turn-on time	$t_{on}$		—	0.4	—	$\mu\text{s}$
	Storage time	$t_{stg}$		—	4.0	—	
	Fall time	$t_f$		—	0.6	—	

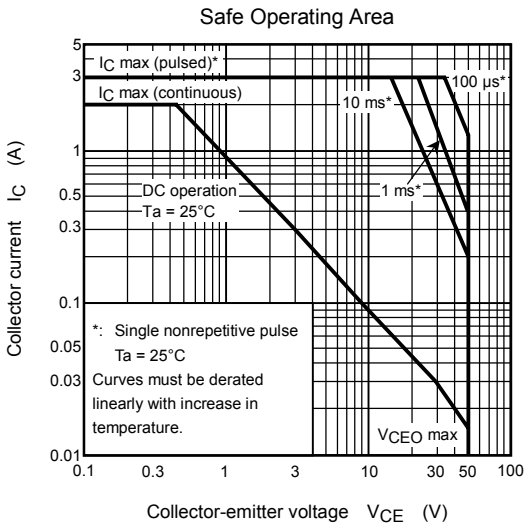
## Marking



## Explanation of Lot No.







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